

## T6421 SERIES

High-reliability discrete products and engineering services since 1977

### **BIDIRECTIONAL TRIODE THYRISTORS**

### FEATURES

- Available as "HR" (high reliability) screened per MIL-PRF-19500, JANTX level. Add "HR" suffix to base part number.
- Available as non-RoHS (Sn/Pb plating), standard, and as RoHS by adding "-PBF" suffix.

#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Repetitive peak off-stage voltage, gate open			
(T <sub>J</sub> = -65 to +100°C)			
T6421B	V <sub>DRM</sub>	200	Volts
T6421D	V DRM	400	Volts
T6421M		600	
T6421N		800	
<b>RMS on-state current</b> (conduction angle = $360^{\circ}$ , $T_{c} \le 65^{\circ}$ C)	I <sub>T(RMS)</sub>	30	Amps
Peak non-repetitive surge current (One Cycle, 60Hz)	I <sub>TSM</sub>	300	Amps
Circuit fusing considerations	l <sup>2</sup> t		A <sup>2</sup> s
(T <sub>1</sub> = -65 to +100°C, t = 1.25 to 10ms)		450	AS
Peak gate power (pulse width = 1.0µs)	P <sub>GM</sub>	40	Watts
Average gate power	P <sub>G(AV)</sub>	0.75	Watts
<b>Peak gate current</b> (pulse width $\leq 1.0 \mu s$ )	I <sub>GM</sub>	2	Amps
Operating junction temperature range	TJ	-65 to +100	°C
Storage temperature range	T <sub>stg</sub>	-65 to +150	°C
Stud torque		30	In. lb.

#### THERMAL CHARACTERISTICS

Characteristics	Symbol	Max	Unit
Thermal resistance, junction to case	R <sub>eJC</sub>	1.0	°C/W

#### **ELECTRICAL CHARACTERISTICS** (T<sub>c</sub> = 25°C and either polarity of MT2 to MT1 voltage, unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Peak off state current (V <sub>D</sub> = V <sub>DRM</sub> , gate open, T <sub>J</sub> = 100°C	I <sub>DRM</sub>	-	-	4	mA
Peak on-state voltage (either direction) (I <sub>TM</sub> = 100A peak)	V <sub>TM</sub>	-	2.1	2.5	Volts
DC gate trigger current (continuous dc) $(V_D = 12V, R_L = 30\Omega)$ MT2(+), G(+); MT2(-), G(-) MT2(+), G(-); MT2(-), G(+)	I <sub>GT</sub>	-	20 35	50 80	mA
<b>DC gate trigger voltage</b> (continuous dc), all trigger modes ( $V_D = 12V$ , $R_L = 30\Omega$ ) ( $V_D = Rated V_{DRM}$ , $R_L = 125\Omega$ , $T_c = 100$ °C)	V <sub>GT</sub>	- 0.2	1.35 -	2.5	Volts
Holding current ( $V_D$ = 12V, gate open, I <sub>T</sub> = 150mA)	IH	-	-	60	mA
Gate controlled turn on time ( $V_D$ = Rated $V_{DRM}$ , $I_{TM}$ = 45A, $I_{GT}$ = 200mA, rise time = 0.1µs)	t <sub>gt</sub>	-	1.7	3	μs



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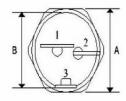
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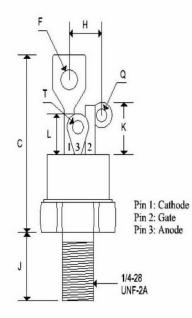
### BIDIRECTIONAL TRIODE THYRISTORS

Critical rate of rise of commutating voltage(commutating di/dt = 16A/ms, gate unenergized, $V_D$ = Rated $V_{DRM}$ , $I_{T(RMS)}$ = 30A, $T_c$ = rated value from figure 1)	dv/dt(c)	3	20	-	V/µs
Critical rate of rise of off-state voltage					
( $V_D$ = Rated $V_{DRM}$ , gate open, exponential waveform, $T_C$ = 100°C)					
T6421B	dv/dt	40			V/µs
T6421D		25	-	-	
T6421M		20			

### MECHANICAL CHARACTERISTICS

Case	TO-48 ISO
Marking	Alpha-numeric
Polarity	Cathode is stud





		T0-4	8 ISO	
	Inc	Inches		neters
	Min	Max	Min	Max
A	0.551	0.559	14.000	14.200
В	0.501	0.505	12.730	12.830
C	-	1.280		32.510
F		0.160		4.060
Η	-	0.265	-	6.730
J	0.420	0.455	10.670	11.560
K	0.300	0.350	7.620	8.890
L	0.255	0.275	6.480	6.990
Q	0.055	0.085	1.400	2.160
Τ	0.135	0.150	3.430	3.810



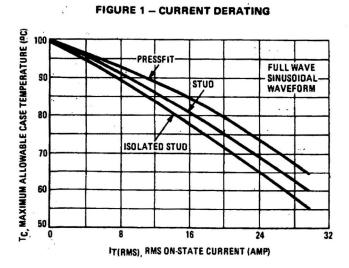
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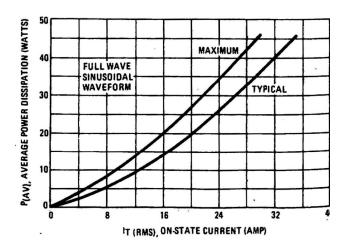
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